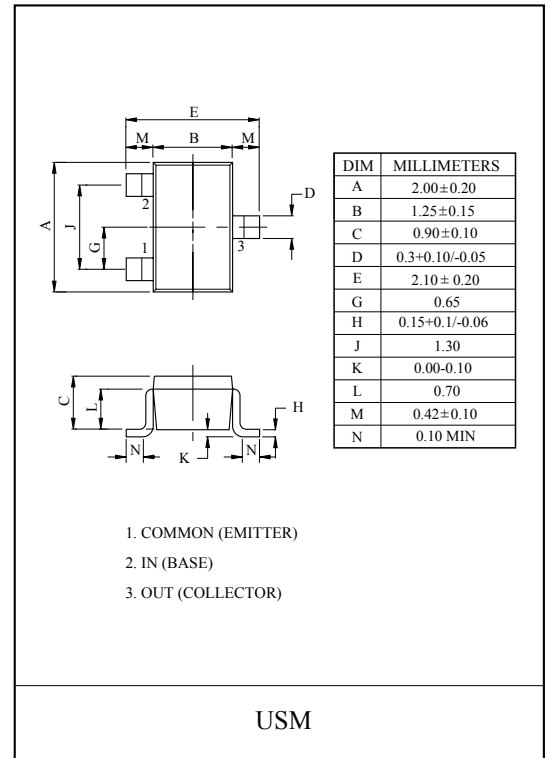
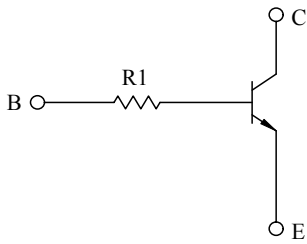


SWITCHING APPLICATION.
INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

FEATURES

- With Built-in Bias Resistors.
- Simplify Circuit Design.
- Reduce a Quantity of Parts and Manufacturing Process.
- High Packing Density.

EQUIVALENT CIRCUIT



MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	100	mA

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector Power Dissipation	P_C	100	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C

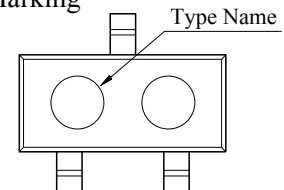
ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V, I_E=0$	-	-	100	nA	
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	-	-	100	nA	
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=1mA$	120	-	-		
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=0.5mA$	-	0.1	0.3	V	
Transition Frequency	f_T^*	$V_{CE}=10V, I_C=5mA$	-	250	-	MHz	
Input Resistor	KRC410	R_1		-	4.7	-	kΩ
	KRC411			-	10	-	
	KRC412			-	100	-	
	KRC413			-	22	-	
	KRC414			-	47	-	

MARK SPEC

TYPE	KRC410	KRC411	KRC412	KRC413	KRC414
MARK	NK	NM	NN	NO	NP

Marking

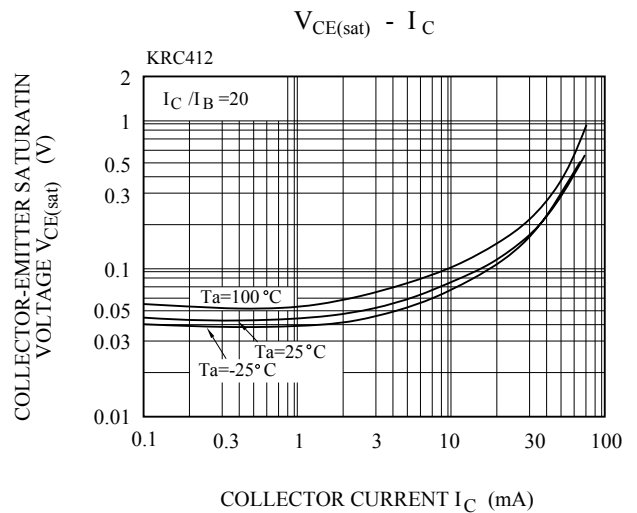
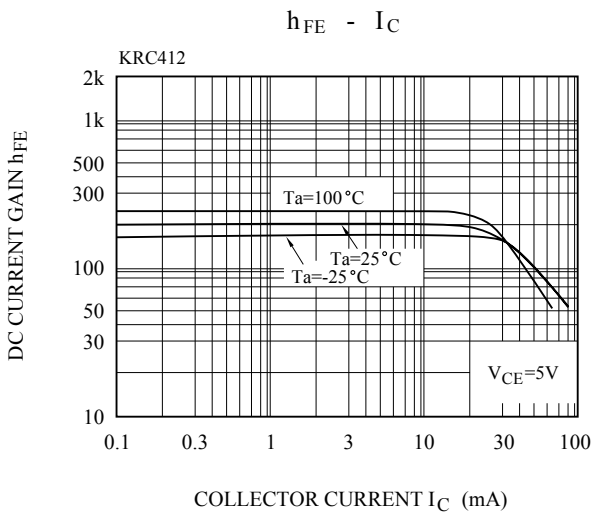
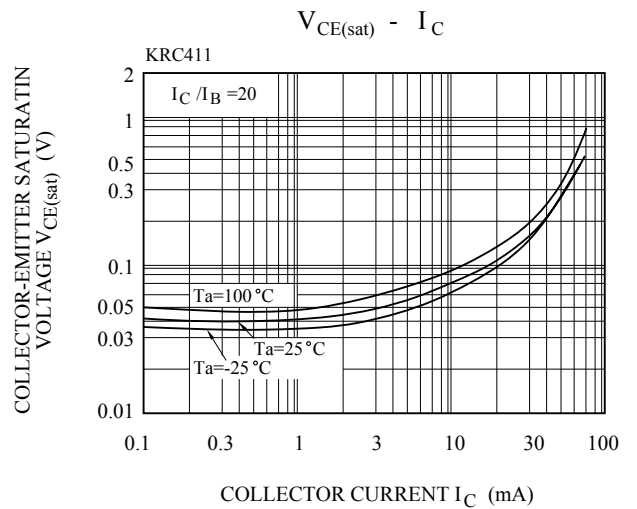
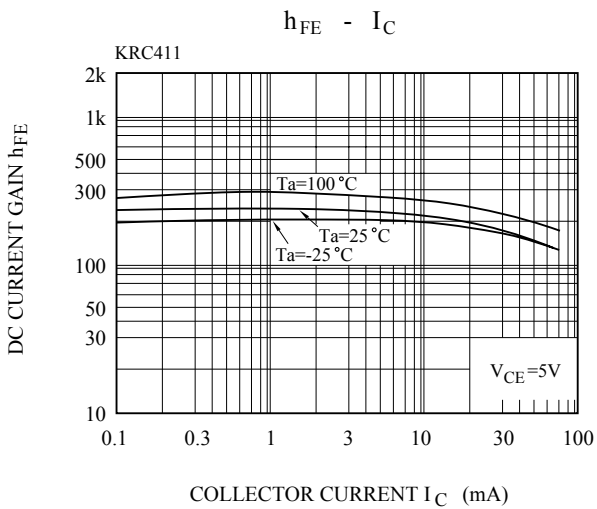
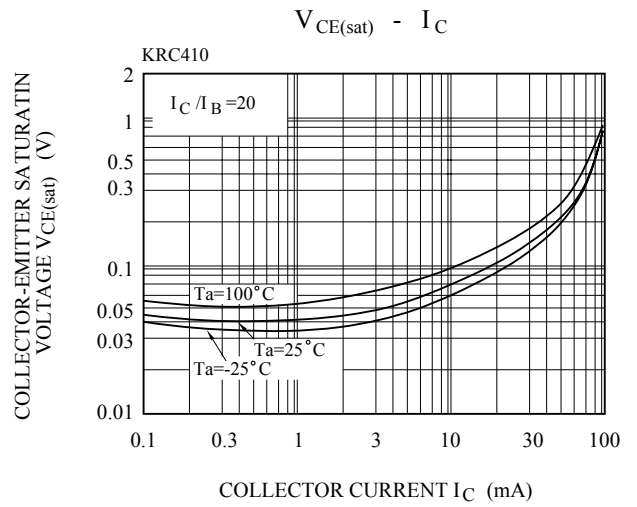
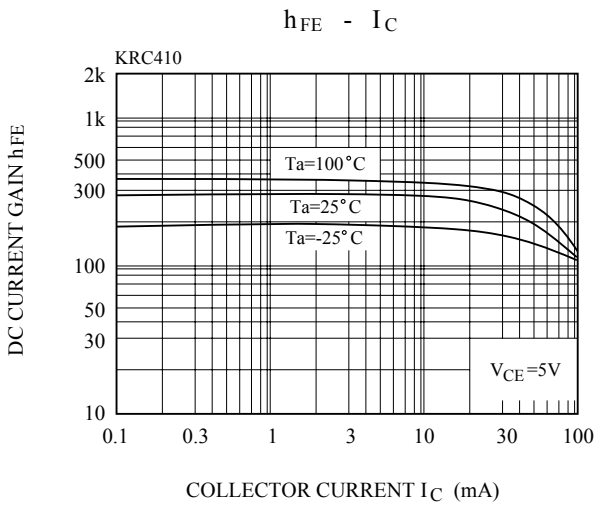


KRC410~KRC414

ELECTRICAL CHARACTERISTICS (Ta=25°C)

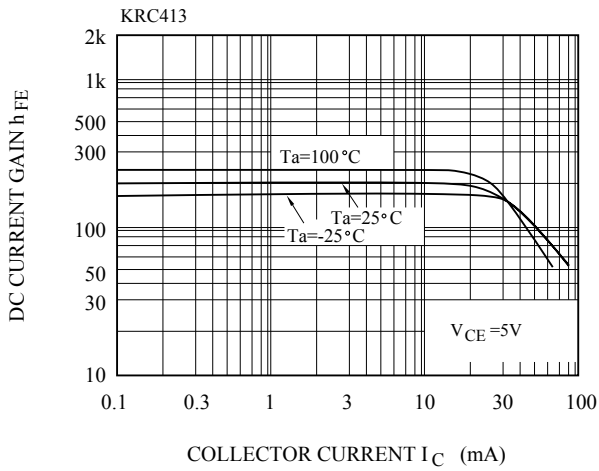
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Switching Time	Rise Time	KRC410	$V_O=5V$ $V_{IN}=5V$ $R_L=1k\Omega$	-	0.025	-	μS
		KRC411		-	0.03	-	
		KRC412		-	0.3	-	
		KRC413		-	0.06	-	
		KRC414		-	0.11	-	
	Storage Time	KRC410		-	3.0	-	
		KRC411		-	2.0	-	
		KRC412		-	6.0	-	
		KRC413		-	4.0	-	
		KRC414		-	5.0	-	
	Fall Time	KRC410		-	0.2	-	
		KRC411		-	0.12	-	
		KRC412		-	2.0	-	
		KRC413		-	0.9	-	
		KRC414		-	1.4	-	

KRC410~KRC414

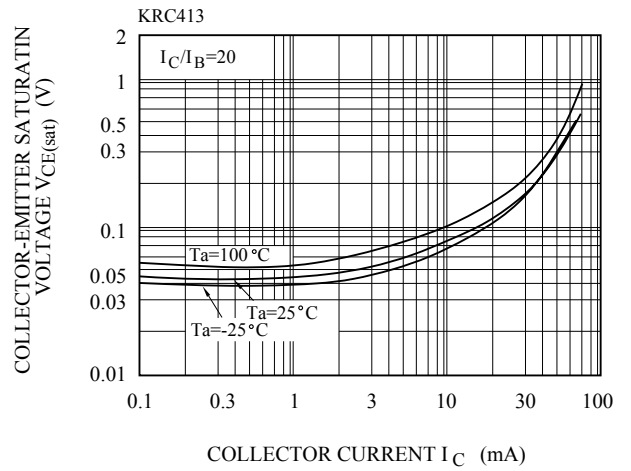


KRC410~KRC414

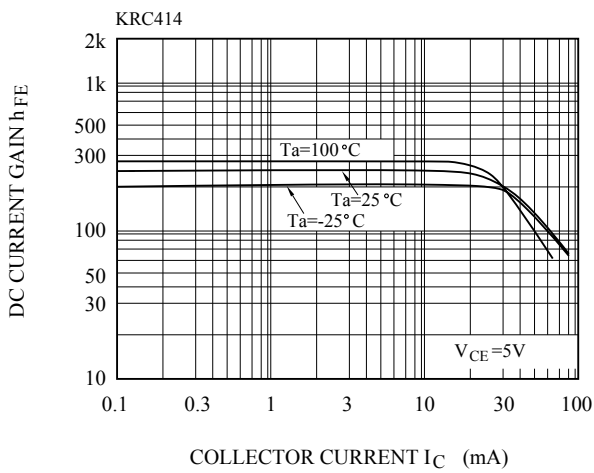
$h_{FE} - I_C$



$V_{CE(sat)} - I_C$



$h_{FE} - I_C$



$V_{CE(sat)} - I_C$

